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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO		
10/604,763 08/14/2003		PING HSU	11286-US-PA	1762		
31561 7	7590 12/22/2004		EXAM	EXAMINER		
•	UN INTELLECTUAL	MALDONADO, JULIO J				
7 FLOOR-1, 1 ROOSEVELT	NO. 100 ROAD, SECTION 2		ART UNIT	PAPER NUMBER		
TAIPEI, 100	•		2823			
TAIWAN			DATE MAILED: 12/22/200	4		

Please find below and/or attached an Office communication concerning this application or proceeding.

		· -	Application No.	Applicant(s)				
			10/604,763	HSU ET AL.				
	Office Action Summary	Ī	Examiner	Art Unit				
			Julio J. Maldonado	2823				
 Period for	The MAILING DATE of this communication of the commu	nication appe	ars on the cover sheet w	th the correspondence a	ddress			
THE MA - Extension after SD - If the pe - If NO pe - Failure to	RTENED STATUTORY PERIOD F AILING DATE OF THIS COMMUN ons of time may be available under the provision K (6) MONTHS from the mailing date of this com- priod for reply specified above is less than thirty ( eriod for reply is specified above, the maximum is to reply within the set or extended period for repl by received by the Office later than three months patent term adjustment. See 37 CFR 1.704(b).	IICATION. s of 37 CFR 1.136 munication. 30) days, a reply v statutory period wil y will, by statute, o	i(a). In no event, however, may a r within the statutory minimum of thin I apply and will expire SIX (6) MON rause the application to become AB	eply be timely filed by (30) days will be considered time THS from the mailing date of this BANDONED (35 U.S.C. § 133).				
Status								
1)⊠ R	esponsive to communication(s) fil	ed on 10 Oc	tober 2004.					
	print,							
-	Since this application is in condition for allowance except for formal matters, prosecution as to the ments is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.							
Disposition	n of Claims							
4a 5)⊠ C 6)⊠ C 7)⊠ C	laim(s) <u>1-20</u> is/are pending in the a) Of the above claim(s) is/a laim(s) <u>1-16</u> is/are allowed. laim(s) <u>17</u> is/are rejected. laim(s) <u>18-20</u> is/are objected to. laim(s) are subject to restri	are withdraw						
Application	n Papers							
9)□ Th	e specification is objected to by the	ne Examiner.						
10)∐ Th	0)☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.							
Ap	oplicant may not request that any obje	ection to the dr	awing(s) be held in abeyan	ce. See 37 CFR 1.85(a).				
Re	eplacement drawing sheet(s) including	g the correctio	n is required if the drawing(	s) is objected to. See 37 C	FR 1.121(d).			
11)∐ Th	e oath or declaration is objected t	o by the Exa	miner. Note the attached	Office Action or form P	TO-152.			
Priority und	der 35 U.S.C. § 119							
a)⊠ 1. 2. 3.	cknowledgment is made of a claim  All b) Some * c) None of:  Certified copies of the priority  Copies of the certified copies  application from the Internation  the attached detailed Office action	documents documents of the priorit	have been received. have been received in A y documents have been (PCT Rule 17.2(a)).	pplication No received in this National	l Stage			
Attachment(s)								
	f References Cited (PTO-892)		4) Interview S	ummary (PTO-413)				
2) 🔲 Notice o	f Draftsperson's Patent Drawing Review (F		Paper No(s	)/Mail Date				
	ion Disclosure Statement(s) (PTO-1449 or o(s)/Mail Date	PTO/SB/08)	5)  Notice of In	formal Patent Application (PT 	O-152)			

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#### **DETAILED ACTION**

### Allowable Subject Matter

1. The indicated allowability of claim 17 is withdrawn in view of the newly discovered reference(s) to Kleinhenz et al. (U.S. 6,140,175). Rejections based on the newly cited reference(s) follow.

## Claim Rejections - 35 USC § 103

- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claim 17 is rejected under 35 U.S.C. 103(a) as being unpatentable over Kleinhenz et al. (U.S. 6,140,175).

Kleinhenz et al. (Figs.1-13) teach a method to form a deep trench capacitor including the steps of providing a substrate (11); forming a plurality of deep trenches in the substrate (11), and the deep trenches (11) arranging into a plurality of columns, wherein the deep trench and the neighboring deep trench that are at a greater distance apart on a same column is an active region (Fig.15), and a border of each deep trench that is adjacent to the active region is a first region; forming a first conductive layer (21) in a lower part and a middle part of each trench (11); forming a buried strap (141) comprising polysilicon in the first region at the upper part of each deep trench; and forming a second conductive layer (100) in the upper part of each deep trench (11) outside the first region, wherein the first conductive layer (21) and the second

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conductive layer (100) serve as the electrode of the deep trench capacitor (column 3, line 45 – column 5, line 12).

Kleinhenz et al. fail to expressly teach wherein said buried strap comprises undoped silicon. However, Gustin et al. to U.S. 6,828,192 B2 teach a method of forming trench capacitors having buried straps, wherein said straps can be undoped silicon (column 6, lines 13 – 46). Furthermore, Chidanbarrao et al. to U.S. 2003/0013259 A1 teach forming deep trench capacitors having undoped silicon buried straps ([0045]). Therefore, it would have been obvious to one of ordinary skill in the art that the embodiment described in Kleinhenz et al. is open to encompass forming an undoped silicon layer and forming a second conductive layer as claimed.

### Allowable Subject Matter

- 4. Claims 1-16 are allowed.
- 5. Claim 18-20 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.
- 6. The following is a statement of reasons for the indication of allowable subject matter: the prior art fails to teach forming an undoped semiconductor layer in an upper part of each of the plurality of deep trenches at a border of each deep trench that is adjacent to an active region; and doping a region of said undoped semiconductor layer except at regions adjacent to said active region to form a second conductive region.

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#### Conclusion

7. Any inquiry concerning this communication or earlier communications from the examiner should be directed to examiner Julio J. Maldonado whose telephone number is (571) 272-1864. The examiner can normally be reached on Monday through Friday.

8. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Olik Chaudhuri, can be reached on (571) 272-1855. The fax number for this group is 703-872-9306 for before final submissions, 703-872-9306 for after final submissions and the customer service number for group 2800 is (703) 306-3329. Updates can be found at http://www.uspto.gov/web/info/2800.htm.

Julio J. Maldonado Patent Examiner Art Unit 2823

Julio J. Maldonado December 15, 2004

George Fourson
Primary Examiner